Experimental investigation of an eight-qubit unit cell in a superconducting optimization processor

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A superconducting chip containing a regular array of flux qubits, tunable interqubit inductive couplers, an XY-addressable readout system, on-chip programmable magnetic memory, and a sparse network of analog control lines has been studied. The architecture of the chip and the infrastructure used to control it were designed to facilitate the implementation of an adiabatic quantum optimization algorithm. The performance of an eight-qubit unit cell on this chip has been characterized by measuring its success in solving a large set of random Ising spin-glass problem instances as a function of temperature. The experimental data are consistent with the predictions of a quantum mechanical model of an eight-qubit system coupled to a thermal environment. These results highlight many of the key practical challenges that we have overcome and those that lie ahead in the quest to realize a functional large-scale adiabatic quantum information processor.

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I. INTRODUCTION

Of the known paradigms of quantum computing, those related to quantum annealing (QA) (Refs. 1-5) are unique in that they leverage what ought to be a robust natural phenomenon-the tendency for physical systems to seek and remain in a low-energy configuration. These methods have received considerable theoretical attention of late with claims and counterclaims concerning their ultimate utility.⁶⁻¹⁰ In contrast, they have received relatively little experimental attention. This is a significant concern as data are needed to help clarify the impact of environmental noise upon such approaches to quantum computing.¹¹⁻¹⁹ Experiments have been performed using nuclear magnetic resonance in molecules²⁰ but the prospects for scaling this approach to larger systems are limited. At least one proposal for an adiabatic quantum optimization (AQO) processor based on superconducting flux qubits exists^{21,22} and rudimentary experiments have been performed upon related small-scale devices with fixed qubit and coupler parameters.^{23–25} Experimental investigations of QA in large-scale systems have only ever been performed upon solid-state samples in which the experimenter has no control over the individual couplings between Ising spins.^{26,27} Consequently, there are many open questions regarding how to implement a large-scale programmable QA information processor in practice.

The purpose of this paper is threefold. First, we address some of the practical questions regarding how to design a scalable superconducting AQO information processor. The answers to these questions will then serve as a motivation for the architecture of the device that we have fabricated. Second, we present experimental results from a unit cell on one such chip consisting of eight flux qubits,²⁸ 16 *in situ* tunable inductive interqubit couplers,²⁹ an XY-addressable high-fidelity readout architecture,³⁰ an array of *in situ* programmable flux storage devices addressed by a single flux quantum demultiplexing circuit,³¹ and a sparse network of analog control lines. The data demonstrate that the unit cell can be

used as a computer for solving Ising spin-glass (ISG) problems. Third, we compare experimental data to the results of numerical simulations in order to highlight the fact that, when run very slowly with respect to the adiabatic limit, the performance of the unit cell is influenced by its tendency to thermalize to an environment.

This paper is organized as follows: Sec. II contains a mathematical description of how the physics of an Ising spin glass can be mapped onto superconducting hardware composed of rf-superconducting quantum interference device (SQUID) flux qubits and couplers. Section III contains a brief review of the hardware that has been fabricated and key calibration data from one of the eight-qubit unit cells. This particular unit cell was used to solve a large number of Ising spin-glass problem instances and the results have been summarized in Sec. IV. A dynamical model of the unit cell coupled to a thermal environment is introduced in Sec. V. Section VI contains a brief discussion of the key results of this paper and presents a series of important open questions that have been motivated by this work. The conclusions are summarized in Sec. VII. A table of specific example problem instance settings referred to in Secs. IV and V has been placed in the Appendix.

II. MAPPING ADIABATIC QUANTUM OPTIMIZATION ONTO HARDWARE

We begin by mapping a particular class of optimization problems onto a scalable processor architecture that uses superconducting flux qubits. Significant emphasis will be placed upon minimizing the number of unique *time-dependent* control signals, thus making efficient use of the limited number of externally supplied biases that can possibly be routed to such a processor. On the other hand, it will be assumed that unique *time-independent* control signals can be generated locally on chip using a scalable form of programmable magnetic memory (PMM) that has been described in detail elsewhere.³¹

Let there be an optimization problem of the form

$$E(\vec{s}) = -\sum_{i} h_i s_i + \sum_{i,j>i} K_{ij} s_i s_j, \qquad (1)$$

where $s_i = \pm 1$, $-1 \le h_i \le +1$, and $-1 \le K_{ij} \le +1$. For any given set of h_i and K_{ij} , there exists at least one optimal solution \vec{s}_{gs} that minimizes the objective *E*. Finding \vec{s}_{gs} for such a system of coupled variables can be non-deterministic polynomial-time (NP)-hard.³² Equation (1) can be mapped onto an ISG Hamiltonian,³³

$$\frac{\mathcal{H}_{\rm ISG}}{E_0} = -\sum_i h_i \sigma_z^{(i)} + \sum_{i,j>i} K_{ij} \sigma_z^{(i)} \sigma_z^{(j)}, \qquad (2)$$

where $\sigma_{x(z)}^{(i)}$ are Pauli matrices acting upon spin *i* and E_0 is a convenient energy. When cast in this form, $|\vec{s}_{gs}\rangle$ represents the ground state of the ISG. The objective is to design a physical system that reliably finds $|\vec{s}_{gs}\rangle$.

One possible means of finding $|\vec{s}_{gs}\rangle$ is via the adiabatic method described in Ref. 2. In an idealized picture of AQO, the Hamiltonian of the system at arbitrary time *t* can be expressed as that of a quantum Ising spin glass (QSG). In such a system, there are pairwise magnetic interactions between spins *i* and $j \propto K_{ij}$ and each spin *i* is subjected to a local longitudinal magnetic field $\propto h_i$ and a global transverse magnetic field $\propto \Gamma(t)$,

$$\frac{\mathcal{H}_{\text{QSG}}(t)}{E_0(t)} = -\sum_i h_i \sigma_z^{(i)} + \sum_{i,j>i} K_{ij} \sigma_z^{(i)} \sigma_z^{(j)} - \Gamma(t) \sum_i \sigma_x^{(i)}.$$
 (3)

One finds the lowest energy solution to an optimization problem encoded in the quantities h_i and K_{ij} by guiding the physical system through an evolution path described by $\Gamma(t)$ subject to the following constraints:

$$\Gamma(0) \gg h_i, K_{ij},$$

$$\Gamma(t_f) \ll h_i, K_{ij},$$

where $t_f > 0$ is the run time of the algorithm. Here, it is assumed that the physical system readily reaches its ground state $|\Pi_0\rangle$ at t=0 and, in the best of circumstances, will remain in the ground state throughout the evolution, thus yielding $|\vec{s}_{gs}\rangle$ at $t=t_f$. Understanding the conditions under which adiabaticity is violated, thus yielding final states other than $|\vec{s}_{gs}\rangle$, is a matter of considerable debate at the moment.^{5–10}

It was recognized in Ref. 21 that one could implement a QSG using a network of rf SQUIDs in which some are designed to fulfill the role of qubits and others to fulfill the role of tunable inductive interqubit couplers. The physics of the two lowest-lying states of an isolated flux qubit i can be captured by an effective Hamiltonian,

$$\mathcal{H}_i = -\frac{1}{2} \left[\epsilon_i \sigma_z^{(i)} + \Delta_q \sigma_x^{(i)} \right],\tag{4}$$

where $\epsilon_i = 2|I_q^p|(\Phi_i^x - \Phi_i^0)$ and Δ_q are the bias and tunneling energy, respectively. Here, $|I_q^p|$ represents the magnitude of the supercurrent flowing about the rf-SQUID loop, Φ_i^x is the external flux bias applied to the qubit loop about which the supercurrent flows, and Φ_i^0 represents the qubit degeneracy

point. Upon comparing terms with like symmetry in Hamiltonians (3) and (4), one can see that $\Delta_a/2 = E_0(t)\Gamma(t)$. In order to implement an AQO algorithm in which $\Gamma(t)$ is altered, one must provide a means for tuning Δ_q in situ. This can be accomplished by incorporating at least one dc-SQUID loop into an rf-SQUID body.^{28,34-37} Since we have used the compound-compound Josephson junction (CCJJ) rf SQUID in our experiments,²⁸ let the external flux bias applied to this device be represented by Φ_{ccjj}^x . This leads to the substitution $\Delta_q \rightarrow \Delta_q(\Phi_{ccjj}^x)$ in Hamiltonian (4). Rather unfortunately, $|I_q^p|$ is also a function of Φ_{ccjj}^x in any compound junction rf-SQUID flux qubit: $|I_q^p| \rightarrow |I_q^p(\Phi_{ccjj}^x)|$. Therefore, one does not naturally obtain orthogonal control of ϵ_i and Δ_a via Φ_i^x and Φ_{ccii}^{x} , respectively. This drawback is common to all flux qubits with *in situ* tunable Δ_q that have been reported on in the literature to date. This intrinsic lack of orthogonal control of the two defining parameters of the flux qubit, $|I_q^p|$ and Δ_q , has driven some of the design choices made in implementing the QSG discussed herein.

Assuming that one has a set of flux qubits for which $|I_q^p(\Phi_{ccjj}^x)|$ and $\Delta_q(\Phi_{ccjj}^x)$ are nominally identical, a general time-dependent Hamiltonian for a system of inductively coupled flux qubits can be written as

$$\mathcal{H}_{0}(t) = -\frac{1}{2} \sum_{i} \left[2|I_{q}^{p}(t)| (\Phi_{i}^{x}(t) - \Phi_{i}^{0})\sigma_{z}^{(i)} + \Delta_{q}(t)\sigma_{x}^{(i)} \right] + \sum_{i,j>i} M_{ij}(t) |I_{q}^{p}(t)|^{2} \sigma_{z}^{(i)} \sigma_{z}^{(j)},$$
(5)

where the time dependence of the qubit parameters $|I_q^p|$ and Δ_q is implicitly driven by $\Phi_{ccjj}^x(t)$. In addition, there could be time dependence in the individual qubit-flux biases $\Phi_i^x(t)$ and in the interqubit effective mutual inductances M_{ij} via their control biases $\Phi_{co,ij}^x(t)$.²⁹

One of the virtues of the AQO algorithm is its simplicity, which provides some significant advantages when considering how to implement a processor. Note that Hamiltonian (5) is a function of a *global* bias $\Phi_{ccjj}^{x}(t)$ to which all qubits are uniformly subjected. This is desirable for two reasons: first, Hamiltonian (3) specifies that the transverse field $\Delta_a(t)/2$ $=E_0(t)\Gamma(t)$ be uniform, which then corresponds to all $\Delta_q(\Phi^x_{ccjj})$ being identical. As a corollary, this renders all $|I^p_q(\Phi^x_{ccjj})|$ identical. Second, one can provide uniform Φ^x_{ccjj} to multiple qubits using a single global current bias line, as opposed to one bias line per qubit. This scenario is depicted in Fig. 1 in which the current bias $I_{ccjj}(t)$ drives the fluxes Φ_{ccjj}^{x} in a multitude of qubits. In doing so, one substantially reduces the number of external biases that must be applied to the processor, thus significantly improving the scaling of this particular architecture. Such design choices are most likely necessary in order to realize multiqubit processors that contain more than tens of qubits.

Given the ideal Hamiltonian (3) and the flux-qubit-based device Hamiltonian (5), one must now map the problem specification, embodied by h_i and K_{ij} in Eq. (1), onto external control parameters. This can be accomplished by scaling Hamiltonian (5) and then performing a term-by-term comparison to Hamiltonian (3). A convenient scaling factor is the interqubit coupling energy when a coupler is set to provide

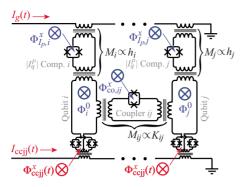


FIG. 1. (Color online) Mapping of ISG problems, specified by a set of values denoted as h_i and K_{ij} , onto superconducting hardware. Two qubits, two $|I_q^p|$ compensators, and one interqubit coupler are shown. A global current bias $I_{ccjj}(t)$ provides the fluxes $\Phi_{ccjj}^x(t)$ that drive the annealing process to multiple CCJJ rf-SQUID flux qubits. Interqubit coupling is mediated by tunable mutual inductances $M_{ij} \propto K_{ij}$ that are controlled by static fluxes Φ_i^x and time-dependent flux biases driven by a global current bias $I_g(t)$. The latter signals are mediated to each qubit via tunable mutual inductances $M_i \propto h_i$ that are controlled by static fluxes Φ_i^x .

maximum antiferromagnetic (AFM) coupling, $M_{ij}(\Phi_{\text{co},ij}^x)$ = M_{AFM} . Define this energy scale as $J_{\text{AFM}}(t) \equiv M_{\text{AFM}} |I_q^p(t)|^2$. Rearranging Hamiltonian (5) yields

$$\frac{\mathcal{H}_0(t)}{J_{\text{AFM}}(t)} = -\sum_i h_i \sigma_z^{(i)} + \sum_{i,j>i} K_{ij} \sigma_z^{(i)} \sigma_z^{(j)} - \Gamma(t) \sum_i \sigma_x^{(i)},$$
(6a)

$$h_{i} = \frac{|I_{q}^{p}(t)|(\Phi_{i}^{x}(t) - \Phi_{i}^{0})}{M_{\text{AFM}}|I_{q}^{p}(t)|^{2}} = \frac{\Phi_{i}^{x}(t) - \Phi_{i}^{0}}{M_{\text{AFM}}|I_{q}^{p}(t)|},$$
 (6b)

$$K_{ij} = \frac{M_{ij}(t)|I_q^p(t)|^2}{M_{\rm AFM}|I_q^p(t)|^2} = \frac{M_{ij}(t)}{M_{\rm AFM}},$$
(6c)

$$\Gamma(t) = \frac{\Delta_q(t)}{2J_{\text{AFM}}(t)}.$$
(6d)

In order to solve a particular optimization problem, h_i and K_{ij} must be *time independent*. According to Eq. (6c), one must hold all M_{ij} constant during operation. This is convenient as it obviates the application of individually tailored time-dependent flux bias signals to each interqubit coupler. Rather, one need only apply a static control signal $\Phi_{co,ij}^x$ to each coupler, as depicted in Fig. 1, that can be provided by PMM. On the other hand, according to Eq. (6b), one must apply *time-dependent* qubit-flux biases of the form

$$\Phi_i^x(t) = \Phi_i^0 + h_i \times M_{\text{AFM}} |I_a^p(t)| \tag{7}$$

to render h_i time independent. Thus, it is necessary to provide a custom-tailored time-dependent control signal plus a static offset to every qubit. The static component Φ_i^0 can be provided by PMM. As for the time-dependent component, providing these signals with one external bias per qubit would not constitute a scalable approach for building a mul-

tiqubit processor. Rather, one can take advantage of the fact that, according to Eq. (7), all gubits must receive a control signal with the same time-dependent shape but with customtailored time-independent scale factors $\propto h_i$. A scalable architecture for providing these signals is depicted in Fig. 1 and has been further expounded upon in Ref. 31. Here, a single global current bias $I_{\alpha}(t) = \alpha |I_{\alpha}^{p}(t)|$, where α is a convenient scale factor, is coupled to multiple qubits via in situ tunable mutual inductances of magnitude $M_i \equiv h_i M_{AFM} / \alpha$. The very same type of device that is used to provide in situ tunable interqubit coupling²⁹ can be retooled to provide coupling between flux qubits and a global bias line. Moreover, each M_i can be controlled with a static flux bias $\Phi^x_{I_n,i}$ provided by PMM. We will refer to this architecture as persistent current $(|I_a^p|)$ compensation, as it is a means of compensating for changing $|I_a^p(t)|$ such that the ISG problem specified by h_i and K_{ii} remains on target throughout annealing.

To summarize up to this point, a prescription for implementing AQO to solve ISG problems using a network of inductively coupled CCJJ rf-SQUID flux qubits has been presented. A problem specified by a set of h_i and K_{ij} can be embedded in the hardware using time-independent interqubit couplings controlled by PMM and time-dependent qubit-flux and CCJJ biases. The qubit-flux bias signals can be supplied using a combination of static flux offsets provided by PMM and a single global signal $I_g(t)$ that is applied to each qubit through *in situ* tunable couplers that are also controlled by PMM. The CCJJ bias can, in principle, also be provided to all qubits simultaneously using a single global control signal.

III. DEVICE ARCHITECTURE AND CALIBRATION

With the mapping of the AQO algorithm onto hardware completed, we turn to a high-level description of a superconducting chip whose architecture embodies that algorithm. All of the principal components of the processor, namely, the qubits,²⁸ couplers,²⁹ readout,³⁰ and PMM (Ref. 31) have been described in detail in other publications. As such, we will only provide brief summaries of the important points as pertaining to the functioning of the collective system herein.

As stated previously, we have incorporated CCJJ rf-SQUID flux qubits in our design.²⁸ A schematic of an isolated flux qubit with the two external bias controls relevant for this study is shown in Fig. 2(a). This particular qubit is robust against fabrication variations in the Josephsonjunction critical currents and facilitates the homogenization of the net critical current among a population of such qubits. This device also contains an inductance (*L*) tuner that can be used to compensate for variations in qubit inductance due to fabrication and from tuning the interqubit couplers.²⁹ To each qubit we have added an $|I_q^p|$ compensator, as introduced in Sec. II. We have provided PMM to flux bias the two minor lobes of each CCJJ,²⁸ the *L* tuner, the $|I_q^p|$ compensator, and the qubit body (Φ_i^0) for all qubits on the chip.³¹

The chip that was used for this study was composed of 16 eight-qubit unit cells that were tiled on a 4×4 square grid. To limit the scope of this paper, we focus upon a single unit cell near the center of the chip. A discussion of the complete processor, with multiple unit cells acting in concert, will be

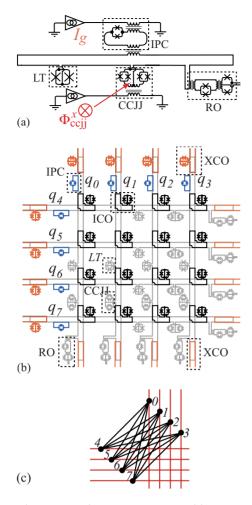


FIG. 2. (Color online) Device schematic. (a) A single CCJJ rf SQUID with the two time-dependent biases relevant for this study. The flux bias $\Phi_{ccjj}^{x}(t)$ drives the annealing process. The global $|I_q^p|$ -compensation bias is provided by $I_g(t)$. (b) Schematic layout of the eight-qubit unit cell. Qubits are shown in gray. Example readout, CCJJ, *L* tuner (LT), $|I_q^p|$ compensator (IPC), internal coupler (ICO), and portions of external couplers (XCO) have been noted. (c) Graph representation of the hardware connectivity. Qubits are represented by vertices (solid dots) and couplings by edges (solid lines). Dark (shaded) edges correspond to ICO (XCO) couplings.

reserved for a future publication. A schematic layout of the unit cell is shown in Fig. 2(b). Qubits are depicted as extended horizontal and vertical loops with 16 compound Josephson junction (CJJ) couplers located at the intersections of the qubits. Additional couplers at both extrema of the qubit bodies facilitate connections to qubits in neighboring unit cells to the left, right, top, and bottom. These latter couplers were set to zero coupling to isolate the single unit cell for this study. Each qubit was connected to its own quantum flux parametron (QFP) enabled readout.^{28,30} Not shown in Fig. 2(b) are the PMM elements, the demultiplexing tree for addressing the PMM or the analog bias lines used to calibrate and operate the unit cell.

A simplified representation of the hardware connectivity is depicted in Fig. 2(c). Here, qubits and couplers correspond to the vertices and edges of a graph.³⁸ As with the unit-cell schematic, this eight-vertex graph can be tiled to the left,

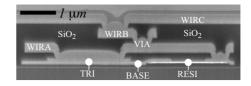


FIG. 3. Scanning electron micrograph of fabrication cross section. Superconducting Nb layers identified as BASE, WIRA, WIRB, and WIRC. Resistive TiPt layer identified as RESI. Planarized dielectric denoted as SiO₂. An example Josephson-junction trilayer and a via between WIRA and WIRB have been denoted as TRI and VIA, respectively.

right, top, and bottom in order to generate larger graphs. Each vertex is connected to a minimum (maximum) of four (six) other vertices, depending on the number and arrangement of unit cells used to form a larger graph. This hardware does not provide full connectivity within a population of N qubits in which each physical qubit is connected to N-1 other physical qubits. This limitation can potentially be overcome, at the cost of reducing the number of unique vertices $\langle N$, by using a ferromagnetically coupled chain of physical qubits to form a single logical qubit, as suggested in Ref. 22.

The chip used in these experiments was fabricated on an oxidized Si wafer with Nb/Al/Al₂O₃/Nb trilayer junctions and four Nb wiring layers separated by planarized plasmaenhanced chemical vapor deposited SiO₂. A scanning electron micrograph of the fabrication cross section can be found in Fig. 3. The Nb metal layers are referred to as BASE, WIRA, WIRB, and WIRC, from bottom to top, respectively. Flux-qubit wiring was primarily located in WIRB and consisted of 2- μ m-wide leads arranged as an approximately 900- μ m-long differential microstrip located 200 nm above a ground plane in WIRA. Coupler wiring was primarily located in WIRC, stacked on top of the qubit wiring to provide inductive coupling. PMM flux storage loops were implemented as stacked spirals of 13–20 turns of 0.25- μ m-wide wiring with 0.25 μ m separation in BASE and WIRA (WIRB). Stored flux was picked up by one-turn washers in WIRB (WIRA) and fed into transformers for flux-biasing devices. External control lines were mostly located in BASE and WIRA. Resistors that were used in the PMM demultiplexing circuit were made from a TiPt layer referred to as RESI. All of these control elements resided below a ground plane in WIRC. The ground planes under the qubits and over the PMM/external control lines were electrically connected using extended vias in WIRB so as to form a nearly continuous superconducting shield between the analog devices on top and the bias circuitry below. Transformers for biasing qubits, couplers, QFPs, and dc SQUIDs were enclosed in superconducting boxes with BASE and WIRC forming the top and bottom, respectively, and vertical walls formed by extended vias in WIRA and WIRB. Minimally sized openings were placed in the vertical walls through which the bias and target device wiring passed at opposing ends of each box. This design reduced most on-chip parasitic crosstalk to a negligible level.

An optical image of a unit cell completed through the processing of WIRB is shown in Fig. 4(a). One can discern the trenches in which the qubit wiring resides, where the

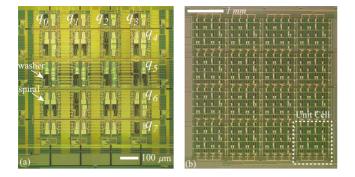


FIG. 4. (Color online) (a) Optical image of an eight-qubit unit cell completed through the processing of WIRB. Qubits, labeled as $q_0 \rightarrow q_7$, reside within the trenches formed by ground plane in WIRA and extended vias in WIRB. PMM elements are visible as spirals and washers between qubits. (b) Optical image of a 4×4 array of eight-qubit unit cells completed through the processing of WIRB. Unit cell shown in (a) is enclosed within the dashed box.

bottom is formed by ground plane in WIRA that is electrically connected to thick vertical walls that are formed by extended vias in WIRB. A number of PMM flux storage and pickup loops are visible as spirals and washers, respectively. The PMM circuitry is not visible in a completed chip as it resides below patches of ground plane in WIRC that are electrically connected at their perimeter to the top of the vertical walls defining the qubit trenches. Thus the qubits (PMM) reside above (below) the nearly contiguous shielding layer in a completed chip. Note that much of the coupler wiring is absent from this image as it resides in WIRC atop the qubit wiring in WIRB.

Tiling of the eight-qubit unit cell to make a larger processor is explicitly demonstrated in Fig. 4(b). One can discern a 4×4 array of eight-qubit unit cells. The particular unit cell used in this study was in the third column and third row. Outside of the field of this image are four blocks of on-chip hysteretic dc SQUIDs, with pickup loops oriented in-plane and orthogonal to the wafer, that are used as magnetometers to measure local fields during active field compensation, as well as wiring channels that run to wire-bonding pads. There are 128 qubits, 352 couplers, and 128 readouts on this processor. These analog components would require a total of 1632 unique biases to operate if no effort was made to develop a scalable control architecture. It would be impractical to build such a processor with so many independent external biases due to circuit density and wirebonding constraints. However, our complete processor, consisting of the analog components enumerated above and 992 PMM elements, requires only 84 pairs of differentially driven external biases.

The chip was enclosed in a superconducting Al shield $(T_c \approx 1.2 \text{ K})$ that was inside two coaxial μ -metal shields. All three shielding layers and the sample were thermalized to the mixing chamber of a pulse tube dilution refrigerator. The refrigerator itself was located inside two room-temperature coaxial μ -metal shields. The magnetic field in the vicinity of the chip was minimized at 3.9 K using triple-axis Cu compensation coils located outside of the Al shield. The array of on-chip dc-SQUID magnetometers surrounding the qubit circuitry was used to infer the magnetic field vector near the

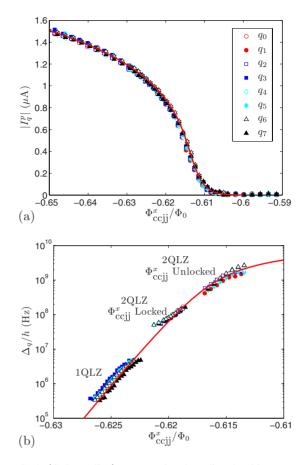


FIG. 5. (Color online) Measured and predicted qubit parameters as a function of Φ_{ccjj}^x . (a) Magnitude of the persistent current $|I_q^p|$. (b) Tunneling energy Δ_q . Solid curves are predictions from the CCJJ rf-SQUID Hamiltonian using independently calibrated device parameters.

processor. The current in the compensation coils was controlled via feedback implemented in software. Once the magnitude of the three-dimensional magnetic field vector had been minimized, the chip was thermally cycled to ≥ 9.5 K to expel trapped flux from the Nb chip ($T_c \approx 9.1$ K) and then cooled to base temperature $T \approx 19$ mK. Thereafter, the current applied to the compensation coils was removed. The residual magnetic field was estimated to be ~ 2 nT(3 nT) perpendicular (parallel) to the plane of the chip.

External biases applied to the chip were provided by a custom-built 14-bit 128-channel differentially driven programmable 50 MHz arbitrary wave-form generator. The signals generated at room temperature were sent into the refrigerator using individually shielded twisted pair wires that were connected to a combination of lumped-element and copper powder filters at the mixing chamber. To minimize the effect of environmental noise and since the AQO algorithm does not require resonant excitation of any element of the circuit, we chose to restrict the bandwidth of these bias lines to 5 MHz. Signals were then routed onto Sn traces on a printed circuit board ($T_c \approx 3.7$ K) and passed onto the chip via Al wire bonds.

A summary of the flux-qubit parameters that are relevant for this study is presented in Fig. 5. Data have been plotted versus normalized flux, where $\Phi_0 \equiv h/2e$ is the flux quantum. The reader is referred to Ref. 28 for a detailed description of the CCJJ rf-SQUID flux qubit and the experimental methods used to obtain $|I_q^p(\Phi_{ccjj}^x)|$. We have obtained $\Delta_q(\Phi_{ccjj}^x)$ using two methods. First, we used the single-qubit Landau-Zener (1QLZ) method³⁹ to yield $2 \times 10^5 \leq \Delta_q/h \leq 10^7$ Hz. The lower and upper bound were set by experimental run-time constraints and the bandwidth of our external control lines, respectively. Second, we ran two-qubit Landau-Zener (2QLZ) experiments on pairs of qubits that were strongly coupled with M_{ij} =-2.82 pH. The Hamiltonian for a pair of qubits, subject to zero net flux bias, can be expressed as

$$\mathcal{H}_{ij} = -\frac{1}{2} [\Delta_i \sigma_x^{(i)} + \Delta_j \sigma_x^{(j)}] + M_{ij} |I_i^p| |I_j^p| \sigma_z^{(i)} \sigma_z^{(j)}.$$
(8)

Data from a 2QLZ experiment yields a spectral gap g, which can be compared to that obtained by solving for the eigenenergies of Hamiltonian (8). The range of g that could be inferred from measurements was also limited by the run-time and bandwidth constraints cited above. In the first variant of 2QLZ, we locked the target Φ_{ccjj}^x biases of the qubits together. Assuming that $\Delta_i = \Delta_j \equiv \Delta_q$, one can use Hamiltonian (6a) to solve for $\Delta_q(\Phi_{ccjj}^x)$ given the independently calibrated $g(\Phi_{ccjj}^x)$, $|I_i^p(\Phi_{ccjj}^x)|$, and $|I_j^p(\Phi_{ccjj}^x)|$. This procedure proved effective for extracting $5 \times 10^7 \leq \Delta_q/h \leq 2 \times 10^8$ Hz. In the second variant of 2QLZ, we targeted $\Phi_{ccjj}^x = -0.6235\Phi_0$ for qubit *i* (a bias for which we have calibrated Δ_i using the 1QLZ method) and scanned the target Φ_{ccjj}^x of qubit *j*. We then used Hamiltonian (6a) to solve for $\Delta_j = \Delta_q(\Phi_{ccjj}^x)$ given the independently calibrated $g(\Phi_{ccjj}^x)$, $\Delta_i(-0.6235\Phi_0)$, $|I_i^p(-0.6235\Phi_0)|$, and $|I_j^p(\Phi_{ccjj}^x)|$. This procedure proved effective for extracting $4 \times 10^8 \leq \Delta_q/h \leq 3 \times 10^9$ Hz.

Prior to collecting the data shown in Fig. 5, we had fully exercised the CCJJ minor lobe and *L*-tuner biases on each of these qubits in order to homogenize $|I_q^p(\Phi_{ccjj}^x)|$ at $\Phi_{ccjj}^x/\Phi_0 = -0.6146$ and -0.6325 among the eight qubits. Residual discrepancies between $|I_q^p|$ and Δ_q of different qubits at arbitrary Φ_{ccjj}^x were attributed to small variations in the mutual inductance between the global CCJJ current bias line and the individual qubits.

The theoretical predictions from a quantum-mechanical Hamiltonian describing the CCJJ rf SQUID, as given by Eqs. (5a)–(5d) in Ref. 28, are shown as solid curves in Fig. 5. The model results were obtained using the means of the independently calibrated CCJJ rf-SQUID parameters, namely, the body inductance $L_{body}=339\pm3$ pH, CCJJ loop inductance $L_{ccjj}=26\pm1$ pH, critical current $I_q^c=3.355\pm0.040$ μ A, and capacitance $C_q=182\pm4$ fF. Given that the experimental data agree with a multilevel quantum mechanical of the CCJJ rf SQUID whose input parameters were independently calibrated, we are confident in our identification of these devices as flux qubits.²⁸

The interqubit couplers and $|I_q^p|$ compensators on this chip were calibrated according to the methods described in Ref. 29. The experimental data are summarized in Fig. 6. From the set of calibrations for all 352 interqubit couplers on the chip, we determined that the smallest maximum AFM coupling was $M_{\rm AFM} = 1.88 \pm 0.03$ pH, which was readily achiev-

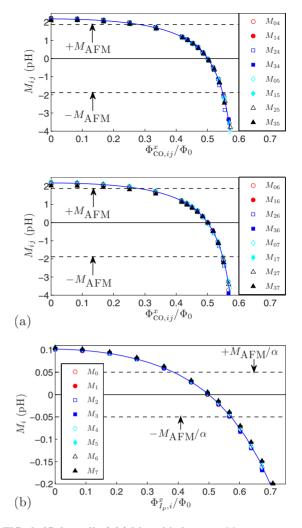


FIG. 6. (Color online) (a) Mutual inductance M_{ij} versus coupler flux bias $\Phi_{co,ij}^x$ for all 16 interqubit couplers in the unit cell. Solid curves are the theoretical M_{ij} obtained using the mean of the individual coupler fit parameters. (b) Mutual inductance M_i versus $|I_q^p|$ -compensator flux bias $\Phi_{I_pi}^x$. Solid curve is the theoretical M_i obtained using the mean of the individual $|I_q^p|$ -compensator fit parameters.

able for all sixteen couplers within the unit cell used in this study. We chose this value of M_{AFM} to define the energy J_{AFM} introduced in Sec. II. Likewise, from the complete set of 128 $|I_q^p|$ compensators on this chip we determined that the maximum usable AFM coupling was $\max|M_i| = 0.100 \pm 0.002$ pH. We found it convenient to use the scale factor $\alpha = 2 \times M_{AFM} / \max|M_i| = 37.6$ to scale the I_q^p compensation signals, as discussed in Sec. II.

Finally, to characterize the readout fidelity of the unit cell, we set all interqubit couplers to zero coupling and then sequentially prepared and read all $2^8=256$ possible final spin configurations $|\vec{s}\rangle = |s_0 \ s_1 \dots s_7\rangle$, with $s_i = \pm 1$. This was accomplished by initializing the qubits in the presence of a bias vector of the form $\vec{\epsilon} \propto (s_0 \ s_1 \dots s_7)$. We prepared each configuration and read the state of the unit cell 1000 times using two repeated reads of each dc SQUID.³⁰ The results of one iteration of this fidelity check are shown in Fig. 7(a). Here, we have adopted a shorthand notation by converting each

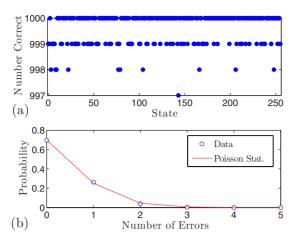


FIG. 7. (Color online) Verification of readout fidelity for the eight-qubit unit cell. (a) Example results from preparing the eight qubits into each of the $2^8=256$ possible final spin configurations and recording the number of correct reads for 1000 repetitions. (b) Probability of observing a given number of errors within 1000 repetitions, as taken from the data in (a). Data have been fit to a Poisson distribution with mean number of errors $\lambda=0.36$.

binary word $|\vec{s}\rangle$ into a decimal number $|\text{State}\rangle$, where

State =
$$\sum_{i=0}^{7} \frac{s_i + 1}{2} 2^{7-i}$$

In the majority of instances, the readout yielded the expected result 1000 times. We never observed more than three errors per 1000 repetitions. Multiple iterations of this check revealed that results for those states that appear to be less than perfect in Fig. 7(a), such as State=143, were not reproducible. Further analysis indicated that these infrequent errors were not due to problems in preparing $|\vec{s}\rangle$. Rather, the errors were most likely generated by the statistical nature of the dc-SQUID switching times.³⁰ The probability of observing a given number of errors within 1000 repetitions, as obtained by taking a histogram of the data in Fig. 7(a), is shown in Fig. 7(b). These results are well described by Poisson statistics with a mean number of errors $\lambda = 0.36$ in 1000 repetitions. We defined the threshold for a number of counts to be statistically significant as three times the square root of the variance, $3\sqrt{\lambda} \approx 2$. One can then deem the fidelity of our readout of the eight-qubit unit cell in these particular experiments to have been $1-3\sqrt{\lambda}/1000=0.998$.

IV. EXPERIMENTAL PROCESSOR PERFORMANCE

To test the performance of the eight-qubit unit cell, we generated a set of 800 unique random ISG problem instances whose h_i and K_{ij} were drawn from a distribution of 15 evenly spaced values within the set

$$h_i, K_{ij} \in [-1 - 6/7 \dots + 6/7 + 1].$$
 (9)

We then took advantage of the symmetry of the physical layout of the qubits and couplers shown in Fig. 2(b) and generated eight permutations of each of the 800 progenitor problems by rotating and reflecting their h_i and K_{ij} embed-

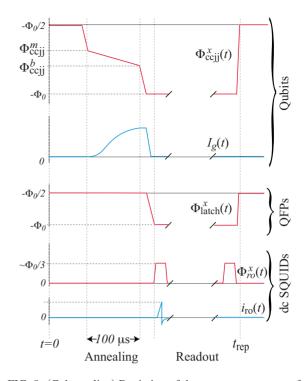


FIG. 8. (Color online) Depiction of the measurement wave form sequence. Only time-dependent biases have been shown. All qubits are subjected to common $\Phi_{ccjj}^{x}(t)$ and $I_g(t)$. All QFPs are subjected to a common $\Phi_{latch}^{x}(t)$. Example dc-SQUID flux Φ_{ro}^{x} and current $i_{ro}(t)$ wave forms shown only for device connected to q_0 .

dings about the center of the unit cell. The result was a test set of 6400 problem instances, each requiring a unique embedding, that were then posed to the hardware. Note that while other researchers have chosen to focus upon particular classes of Ising spin problems, such as random 3-SAT,⁴⁰ MAX-clique,⁴¹ and exact cover,^{2,42} we have found our random ISG problem set to be of great use as it encompasses a broad range of problem classes that could be posed to an AQO processor in practice.

The PMM programming required to set up the processor was rather involved and the details of its implementation are beyond the scope of this paper.³¹ Nonetheless, it is worth recognizing that, for each problem instance, the interqubit coupler biases $\Phi_{co,ij}^x$ and $|I_q^p|$ -compensator biases $\Phi_{I_p,i}^x$ were reset to provide the desired K_{ij} and h_i , respectively. As a consequence of the changing interqubit coupler susceptibility, the *L*-tuner biases also had to be updated to hold the qubit inductance constant, as described in Ref. 28. Finally, the effects of junction asymmetry in the CJJ interqubit couplers and $|I_q^p|$ compensators led to a small offset of each qubit's degeneracy point $\delta \Phi_i^0$, as shown in Ref. 29. These offsets were independently calibrated for each qubit prior to running the processor. To compensate, the PMM controlling the qubit-flux offset Φ_i^0 was updated.

With the details concerning the PMM aside, the analog control signal sequence for implementing the AQO algorithm introduced in Sec. II was quite simple, as depicted in Fig. 8. During the annealing phase, there were only two time-dependent signals applied to the entire unit cell: the CCJJ control signal $\Phi_{ccii}^{x}(t)$ and the $|I_{g}^{p}|$ -compensation signal $I_{g}(t)$.

For simplicity, we chose to use a relatively slow 100- μ s-long linear ramp of $\Phi_{ccjj}^x(t)$ through the region relevant for qubit operation between $\Phi_{ccjj}^m/\Phi_0 = -0.590$ and $\Phi_{ccjj}^b/\Phi_0 = -0.650$, where the superscripts *m* and *b* denote biases for which the CCJJ rf-SQUID potential energy is deep in the monostable and bistable regime, respectively. The aforementioned ramp time was sufficiently long to avoid the loss of ground-state probability to Landau-Zener transitions at anticrossings.^{39,43,44} Experimental data and numerical simulations supporting this latter statement will be discussed in Sec. V. The time-dependent wave form $I_g(t) = \alpha |I_q^p(t)|$, with $\alpha = 37.6$, was constructed by sampling the modeled $|I_q^p[\Phi_{ccjj}^x(t)]|$, shown as the solid curve in Fig. 5(a), at 200 points between Φ_{ccjj}^m and Φ_{ccjj}^b .

At the end of the annealing phase, the final task that involved time-dependent wave forms was that of reading out the state of the unit cell. The states of all eight qubits were simultaneously latched by raising the QFP tunnel barriers in unison using their global bias $\Phi_{\text{latch}}^{x}(t)$.^{28,30} Thereafter, the dc-SQUID current biases and flux biases were modulated to serially read out the state of each QFP. In Fig. 8, only those current and flux bias wave forms for operating the readout connected to q_0 have been depicted. The entire wave-form sequence, including programming of the 992 PMM elements, a 1 ms cooling period following PMM programming, and 1000 repetitions of the anneal and read sequence depicted in Fig. 8 was completed in ≈ 2.5 s.

The key experimental parameter that was varied in this study was the temperature of the processor *T*. We calibrated *T* in situ using macroscopic resonant tunneling (MRT) measurements versus Φ_q^x at $\Phi_{ccjj}^x/\Phi_0 = -0.6238$ using a dwell time of 1 ms on qubits q_0 and q_4 .⁴⁵ At this particular CCJJ bias, the qubits reached thermal equilibrium within the specified dwell time and the resultant population statistics versus Φ_q^x could be fit to the form

$$P_{\rm MRT} = \frac{1}{2} \left\{ 1 + \tanh\left[\frac{2|I_q^p|(\Phi_q^x - \Phi_q^0)}{2k_BT}\right] \right\},\$$

where $|I_q^p| = 1.26 \pm 0.02 \ \mu A$ was obtained from the independent calibration shown in Fig. 5(a) and Φ_q^0 was the independently calibrated qubit-flux offset. This then left only one free parameter, namely, *T*.

The unit cell was tested using the set of 6400 problem instances at three values of T. Each instance was run 1000 times and the probabilities of observing each of the 256 possible $|\vec{s}\rangle$ were recorded. Given the small size of the instances, it was trivial to independently determine $|\vec{s}_{gs}\rangle$. Histograms of the probability of observing the ground state P_{gs} are shown in Fig. 9. The output of numerical simulations shown in these plots will be discussed in Sec. V. Here, the vertical axes correspond to the number of problem instances for which the hardware returned P_{gs} within the bounds of each bin of the histogram. The data taken at T=20 mK, see Fig. 9(a), show an obvious spike in the highest bin, $0.95 < P_{gs} \le 1$, and a tail that appears to be exponentially suppressed at lower P_{gs} . For T=35 mK, see Fig. 9(b), the spike in the highest bin appears diminished and a broad hump in the vicinity of $P_{\rm gs} \sim 0.6$ is observed. Finally, for T=50 mK, see Fig. 9(c), the high P_{gs}

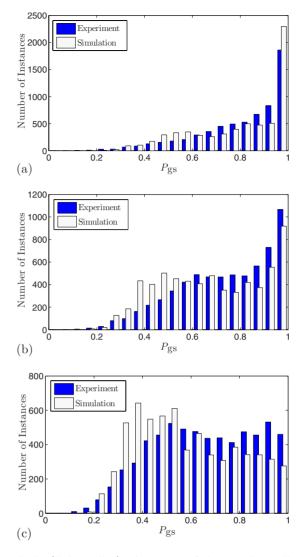


FIG. 9. (Color online) Histograms of the experimentally observed and the simulated probability of finding the system in the ground state P_{gs} from a test involving 6400 unique random ISG instances at three different temperatures: (a) T=20 mK, (b) T=35 mK, and (c) T=50 mK.

spike has been flattened and the broad hump has shifted to slightly lower $P_{\rm gs} \sim 0.5$. Nonetheless, for all three values of T, $P_{\rm gs} > 0.1$ for all instances.

To gain further insight into the source of the structure of the histograms shown in Fig. 9, we selected an exemplary problem instance from each of the three features in the T=35 mK results. Example A from the spike ($P_{gs} \sim 1$), example B from the broad hump ($P_{gs} \sim 0.6$), and example C from the tail ($P_{gs} \sim 0.4$). The instance settings h_i and K_{ij} for these examples are given in the Appendix. We ran each example instance 1000 times at $20 \le T < 100$ mK. A summary of the observed population statistics P is shown in Fig. 10. The output of numerical simulations shown in these plots will be discussed in Sec. V. For examples A, B, and C, a total of 28, 13, and 38 states were observed above the readout resolution threshold at T=91.7 mK, respectively. We have plotted the data for only those states that were observed with P > 0.01 at T=91.7 mK.

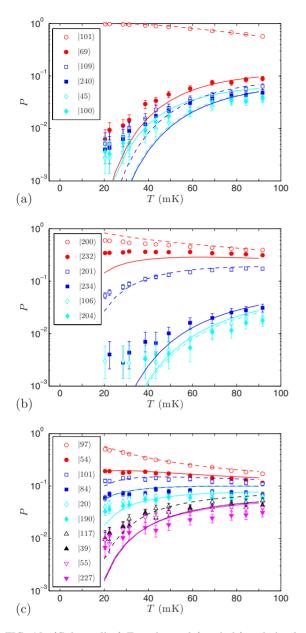


FIG. 10. (Color online) Experimental (symbols) and simulated (curves) probabilities of finding the system in low-energy states. (a) Example A. (b) Example B. (c) Example C. Solid (dashed) curves have been color coded to match filled (hollow) symbols.

The results shown in Fig. 10 indicate that a small number of $|\vec{s}\rangle$ are returned for any given problem instance and that the probability of observing those states evolves smoothly with *T*. To assist in determining why particular states were observed, we have evaluated the objective function $E(\vec{s})$, given by Eq. (1), for examples A, B, and C using the values of h_i and K_{ij} provided in the Appendix. The results have been summarized in Fig. 11. This plot reveals that the ground state $|\vec{s}_{gs}\rangle = |101\rangle$, $|200\rangle$, and $|97\rangle$ for examples A, B, and C, respectively. Likewise, the first excited state(s) can be identified as $|\vec{s}\rangle = |69\rangle$, $|232\rangle$, and the degenerate pair ($|54\rangle$, $|101\rangle$) for examples A, B, and C, respectively. From a comparison of Figs. 10 and 11, one can make two important observations: first, for all three examples the order of the observed states, from most to least probable, *exactly* matches the order

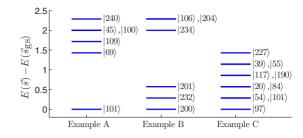


FIG. 11. (Color online) Evaluation of the dimensionless objective function $E(\vec{s})$ [Eq. (1)] for examples A, B, and C. Instance settings are given in the Appendix. Results plotted relative to the lowest value $E(\vec{s}_{gs})$. Spin configurations $|\vec{s}\rangle$ are identified to the right of each level.

when ranked by ascending $E(\vec{s})$. Thus the ground state is the most probable state, the first excited state is the second most probable, and so forth. The only exception is the ordering of $|240\rangle$ and $(|45\rangle, |100\rangle)$ in example A, though this discrepancy is within the noise. Second, there is a preferred order for some of the pairs of degenerate excited states such as $(|54\rangle, |101\rangle)$ and $(|190\rangle, |117\rangle)$ for example C. While the preference for one over the other appears to be subtle, it is nonetheless very reproducible.

To summarize this section of the paper, we have tested an eight-qubit unit cell inside a superconducting processor that embodies an AQO algorithm. The unit cell was subjected to 6400 random ISG problem instances at three temperatures and three representative instances at multiple temperatures. With repeated measurements, the hardware returns a small number of final spin configurations, with the ground state always being the most probable result. The remaining states that are observed correspond to low-lying excited states.

V. SIMULATED PROCESSOR PERFORMANCE

The objective of this section of the paper is to present a physical picture that naturally explains the final distribution of $|\vec{s}\rangle$ that was obtained from any given ISG problem instance that was posed to the hardware. This picture relies upon the invocation of interactions between all eight qubits and a thermal environment. It will be demonstrated that the inclusion of quantum mechanical relaxation⁴⁶ is sufficient to explain the observed distributions.

We have chosen to model this system by neglecting all but the two lowest-lying states in each CCJJ rf SQUID (qubit approximation). Furthermore, we have also assumed that the qubit parameters $|I_q^p(\Phi_{ccjj}^x)|$ and $\Delta_q(\Phi_{ccjj}^x)$ are the same for all qubits and are given by the solid curves in Fig. 5. This latter assumption would not be justified without having first leveraged all of the features of the CCJJ rf SQUID so as to synchronize their qubit parameters to a reasonable level. The low-energy physics of the ideal closed system will then be dictated by Hamiltonian (6a).

Instantaneous eigenspectra as a function of annealing parameter Φ_{ccjj}^x for examples A, B, and C, as generated using Hamiltonian (6a), are shown in Fig. 12. Note the negative sign in front of the independent variable in these plots, which has been inserted such that annealing progresses from left to

right. The eigenenergies E have been plotted relative to the ground-state energy E_0 such that the ground state is coincident with the horizontal axis. The lowest 16 levels have been plotted for examples A and B and the lowest 32 levels for example C. In all cases the eigenspectra have been truncated above the second excited state of an isolated CCJJ rf SQUID, here denoted as E_{rfs} , as Hamiltonian (6a) is not the correct representation of the physics of the closed system beyond this energy. This latter point is of significant practical interest and will receive more attention in Sec. VI.

The states at the onset of annealing have been identified on the left of each plot in Fig. 10. Here, the ground state is denoted as

$$|\Pi_0\rangle = \frac{1}{16} \prod_{i=0}^{7} (|-1\rangle_i + |+1\rangle_i)$$

and is a product of the isolated qubit ground states. There is an octet of first excited states, denoted as $|\Pi_{1,m}\rangle$, which are product states of all qubits in their ground state except a single qubit m in its excited state, $(|-1\rangle_m - |+1\rangle_m)/\sqrt{2}$. Analogously, there are 28 second excited states, denoted as $|\Pi_{2,m,n}\rangle$, in which all but two qubits are found in their ground state. In all cases, the excited states drop in energy with increasing annealing parameter until they reach a minimum in the vicinity of $\Phi_{ccij}^{\vec{x}}/\Phi_0 \sim -0.615$. Each of the minima correspond to a point in the annealing process at which the ground state, initially $|\Pi_0\rangle$, sheds a localized spin configuration $|\vec{s}\rangle$ from the superposition, thus eventually localizing in the solution state $|\vec{s}_{gs}\rangle$. Likewise, the excited states become localized in configurations $|\vec{s}\rangle \neq |\vec{s}_{gs}\rangle$ as they are ejected from the ground state, and then increase in energy to the right of the minima. In a large-scale QSG, this process would give rise to a second-order phase transition between a ground state possessing a high degree of symmetry (a superposition of all $|\vec{s}\rangle$ to the left of the minima and a ground state with broken symmetry (localized in $|\vec{s}_{gs}\rangle$) to the right of the minima. Those $|\vec{s}\rangle$ that were observed with P > 0.01 at T =91.7 mK, as indicated in Fig. 10, have been labeled on the right of each corresponding plot in Fig. 12.

Each plot in Fig. 12 has been marked with a vertical dashed line at $\Phi_{ccjj}^x/\Phi_0 = -0.622$ to roughly delineate where in the annealing process the population statistics appear to freeze. As a crude approximation, one can take the energies of the excited states along this vertical line and calculate Boltzmann occupation factors that roughly agree with the results presented in Fig. 10. However, such a simplistic picture cannot explain the very reproducible disparity between the observed probabilities of excited states that are degenerate along the vertical line.

To begin the discussion of our dynamical model, it is prudent to briefly address what is *not* the source of either the structure of the P_{gs} histograms in Fig. 9 or the nonzero probability of observing excited states in Fig. 10. We argue that none of these observations can be explained by a violation of the adiabatic condition. First, we have studied all 800 progenitor random ISG problems by numerically solving a dynamical model the system described by Hamiltonian (6a) in the absence of environmental noise and subject to the wave

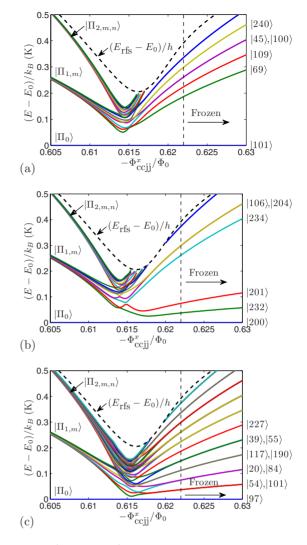


FIG. 12. (Color online) Calculated low-energy eigenspectra versus $-\Phi_{ccjj}^{x}$. (a) Example A. (b) Example B. (c) Example C. Energies have been plotted relative to the ground-state energy E_0 and truncated above that of the second excited state of the CCJJ rf SQUID, $E_{rfs}-E_0$. Initial states are labeled as $|\Pi_0\rangle$, $|\Pi_{1,m}\rangle$, and $|\Pi_{2,m,n}\rangle$ on the left. Final states are labeled as $|\vec{s}\rangle$ on the right. Vertical dashed lines roughly delineate the value of $-\Phi_{ccjj}^{x}$ beyond which the population statistics appear to freeze during annealing.

forms depicted in Fig. 8. These simulations revealed that the 100 μ s CCJJ bias ramp time was sufficiently long as to deem the evolution of the closed system adiabatic, as they always returned P_{gs} =1 to within numerical error. Second, we have experimentally studied examples A, B, and C at multiple CCJJ bias ramp times from 10 μ s to 1 ms and observed relatively little change in the outcome. Bandwidth limits on our apparatus prevented us from studying the system subject to shorter ramp times.

We now turn to a description of the open system model that we have investigated. We wish to first deal with the physics of relaxation and then discuss the effects of dephasing thereafter. Furthermore, we carefully distinguish between AQO, in which the evolution of the closed system can be described as adiabatic, and QA, in which the coupled qubit system exchanges energy with its environment.

EXPERIMENTAL INVESTIGATION OF AN EIGHT-QUBIT...

It has been argued that flux noise is the principal source of decoherence for superconducting qubits of the type included in our circuits.⁴⁵ For solid-state qubits, where materials defects proximate to the qubit body are most likely the intermediaries by which a thermal environment disturbs the state of a qubit, this is best captured by coupling each qubit to its own independent local environment. The Hamiltonian for this open system can be written as

$$\mathcal{H}(t) = \mathcal{H}_0(t) + \frac{1}{2} \sum_{i=0}^{7} 2|I_q^p(t)|Q_i(t)\sigma_z^{(i)},$$
(10)

where $\mathcal{H}_0(t)$ is given by Hamiltonian (6a) and $Q_i(t)$ is an operator that acts upon the environment seen by qubit *i* that has units of flux. Note the factor of $|I_q^p(t)|$ preceding each $Q_i(t)$, which captures the fact that as annealing progresses that the coupling between qubit *i* and environmental flux noise will change. The noise spectral density for the environment surrounding qubit *i* as a function of angular frequency ω can be expressed as⁴⁷

$$S_i(\omega) \equiv (2|I_q^p(t)|)^2 \int dt' e^{i\omega t'} \langle Q_i(t')Q_i(0)\rangle.$$
(11)

For Markovian noise,⁴⁶ the fluctuation-dissipation theorem allows one to write

$$S_i(\omega) = \frac{2 \operatorname{Im}\{L_0(\omega)\}(2|I_q^p(t)|)^2 \hbar \omega}{1 - \exp\left(-\frac{\hbar \omega}{k_B T}\right)},$$
(12)

where $L_0(\omega)$ can be thought of as an inductance per unit bandwidth that is imparted to qubit *i* by its local environment. At a more fundamental level, L_0 must be proportional to the environment's complex magnetic susceptibility summed over all modes.

While there is general consensus that the flux noise power spectral density in superconducting flux qubits is 1/f in nature at very low frequency,⁴⁸ relatively little is known about the form of $S_i(\omega)$ that is appropriate at the high energies required to induce transitions in these qubits. In lieu of a more detailed picture of $S_i(\omega)$, we have chosen to follow a simple but physically reasonable approach by taking the Ohmic approximation in which $\text{Im}\{L_0(\omega)\}$ is treated as a constant. This simple quantum mechanical model of an environment is sufficient for our purposes as its thermally occupied modes will fuel excitations of the eight-qubit system, thus compromising P_{gs} .

To simulate the dynamics of the open system embodied by Hamiltonian (10), we have constructed a numerical model based on a generalized Bloch-Redfield formalism.^{49,50} In this model, one integrates a set of coupled first-order differential equations for the elements of the eight-qubit system's density matrix $\rho(t)$, as given by

$$\partial_t \rho_{mn} = -i\omega_{mn}\rho_{mn} - \sum_{k,l} (R_{mnkl} + M_{mnkl})\rho_{kl}, \quad (13a)$$

$$M_{mnkl} = -\delta_{nk} \langle l | \partial_t | m \rangle - \delta_{ml} \langle n | \partial_t | k \rangle, \qquad (13b)$$

where R_{mnkl} is the so-called Redfield tensor⁵⁰ which is constructed from matrix elements of the flux operators between the eight-qubit states $|m\rangle$ the individual $S_i(\omega)$. These matrix elements, which vary proportional to the number of qubit flips between a pair of states, are what facilitate thermalization of the eight-qubit system. In order to make the numerical work manageable on a personal computer, we kept only the ten lowest-lying states. We have verified that the output of this model in the limit of small Im{ L_0 } matches that of numerically solving the Schrodinger equation.

Our numerical model of the open system contains only one free parameter, namely, $Im\{L_0\}$. One can generate a crude estimate of this parameter based on the width W of a single-qubit lowest-order MRT peak deep in the incoherent regime. From Eq. (9) of Ref. 51,

$$W^2 = \int d\omega S_i(\omega). \tag{14}$$

For the qubits in the circuit studied in this paper, experimental results yielded Gaussian-shaped MRT peaks of width $W/2|I_a^p| \sim 80\mu\Phi_0$ at T=20 mK. Low-frequency drift measurements, of the type described in Ref. 52, revealed lowfrequency flux noise with a one-sided power spectral density that could be fit to the form A^2/f with $A \sim 1 \mu \Phi_0 / \sqrt{\text{Hz}}$. Integrating this 1/f power spectrum over a nominal ten decades in frequency yields a root mean-squared flux noise on the order of $W_{\rm LF}/2|I_q^p| \sim 5\mu\Phi_0$. Therefore, there was an additional $(W-W_{\rm LF})/2|I_q^p| \sim 75\mu\Phi_0$ of integrated flux noise that was not captured by the 1/f portion of the noise spectrum. Assuming that the remainder of $W/2|I_a^p|$ can be attributed to a small white flux noise level that is integrated out to a cutoff $f_c = k_B T / h \sim 460$ MHz, we estimate that the amplitude of the one-sided flux noise spectral density will be on the order of $\delta \Phi_n \sim 3.5 \ n \Phi_0 / \sqrt{Hz}$. This white noise level is well below the detection limits realized in all low-frequency flux noise measurements on SQUIDs reported in the literature to date. Experimental evidence of an even lower white flux noise level in a three-junction rf-SQUID flux qubit has been reported in Ref. 53. In terms of an environmental inductance, our estimate of $\partial \Phi_n$ translates into Im{ L_0 }=47 yH/Hz.

The results of numerical simulations of Eq. (13a) with the estimated $Im\{L_0\}$ and the problem instance settings for examples A, B, and C as a function of T are summarized in Fig. 10. Here, the coloring and format of the curves have been chosen to correspond to the color and fill of the data symbols in those plots, with hollow (solid) points corresponding to dashed (solid) curves. While the match between theory and experiment is not perfect, it is nonetheless clear that the generalized Bloch-Redfield model does provide a reasonable prediction of the populations for all three examples. We believe that most of the discrepancies can be explained by slight errors in problem instance specification, as will be discussed below, and therefore did not pursue any fitting of these data by changing $Im\{L_0\}$. Very importantly, we draw attention to the splitting of the population statistics between the pairs of degenerate excited states $(|54\rangle, |101\rangle)$ and $(|190\rangle, |117\rangle)$ for example C. These features arise quite naturally from the model and are a result of differences in the transition rates between states during the course of annealing, as governed by the quantum-mechanical matrix elements of the flux operators between pairs of states.

In addition to the three example instances, we have simulated all 6400 instances using our model and constructed $P_{\rm gs}$ histograms to compare with the data in Fig. 9. The results of these simulations are summarized in those plots. These simulations yielded the expected general features, specifically the loss of counts from the highest $0.95 < P_{\rm gs} \le 1$ bin to the broad hump centered about $P_{\rm gs} \sim 0.6$ with increasing *T*, and an exponentially suppressed tail at low $P_{\rm gs}$. However, the simulations also yielded more small-scale structure in the histograms than was observed in experiment.

It was hypothesized that slight errors in embedding problem instances in the hardware could have been responsible for the absence of fine structure in the experimental histograms in Fig. 9. The PMM elements responsible for nulling qubit-flux offsets are on-chip digital-to-analog flux converters whose least significant bit (LSB) weights were measured to be $\partial \Phi^{LSB} \approx 38\mu\Phi_0$. Therefore, we could not null qubit offsets Φ_i^{ℓ} to better than $\pm \partial \Phi_q^{LSB}/2$ using PMM. Furthermore, the PMM elements controlling the coupler and $|I_q^p|$ -compensator flux biases, $\Phi_{co,ij}^x$ and $\Phi_{I_p,i}^x$, had LSB weights $\partial \Phi_{co}^{LSB} \approx \partial \Phi_{I_p}^{LSB} \approx 60\mu\Phi_0$. This latter quantity limited the precision to which $K_{ij} \propto M_{ij}$ and $h_i \propto M_i$ could be specified, respectively, thereby distorting problem instances. We have attempted to simulate the effects of the finite precision of our PMM elements on all 6400 problem instances. It was observed that such embedding errors only marginally smoothed out the fine structure in the simulated histograms.

A second potential source of error in embedding problem instances onto the hardware was that due to imperfect setting of the CCJJ control biases that are used to null the effects of Josephson-junction variations.²⁸ Such imperfections give rise to an apparent flux offset in a qubit that varies monotonically with the annealing control, meaning that $\Phi_i^0 \rightarrow \Phi_i^0(\Phi_{ccjj}^x)$ in Eq. (6b), as given by Eq. (B4c) of Ref. 28. Our single-qubit calibration procedures null $|\Phi_i^0(\Phi_{ccjj}^m) - \Phi_i^0(\Phi_{ccjj}^b)|$ to less than $20\mu\Phi_0$, where the biases Φ_{ccjj}^m and Φ_{ccjj}^b straddle the region that is critical for annealing, as depicted in Fig. 8. Thus, while such imperfections will inevitably be present, we nonetheless consider their impact to be subdominant to the errors introduced by the finite precision of the PMM.

Our multiqubit generalized Bloch-Redfield model invokes Ohmic noise spectral densities that extend to high energy, thus providing a mechanism by which each individual qubit can exchange energy with its environment. Within the context of gate model quantum computation (GMQC), highfrequency noise of this type gives rise to the time scale T_1 over which a qubit prepared in its excited state would relax toward thermal equilibrium. In many respects, QA is compromised by the reverse process in which a qubit prepared in its ground state is excited by the environment over a time scale $e^{E_q/k_BT}T_1$, as dictated by the Einstein relation between upward and downward transition rates, where $E_q = \sqrt{\epsilon_q^2 + \Delta_q^2}$ is the excitation energy of a qubit for arbitrary bias conditions. This implies that QA is somewhat more robust against the effects of thermalization than GMQC, although our numerical simulations clearly indicate that the ground-state probability $P_{\rm gs}$ is reduced by these T_1 -related processes. Nonetheless, theoretical studies such as Ref. 50 have concluded that the computation time need not be severely compromised by the presence of such an environment.

One of the key oversights of our generalized Bloch-Redfield model is the role of non-Ohmic low-frequency flux noise, particularly noise spectral densities of the form $S_i(\omega)$ $\propto 1/\omega^{\eta}$ ($\eta > 0$) that are commonly referred to as 1/f noise. Within the context of GMQC, low-frequency flux noise adiabatically manipulates qubit biases, thus leading to dephasing over a time scale denoted as T_{φ} . From the perspective of QA, it is more convenient to envision low-frequency flux noise as being responsible for random flux offsets within each qubit that change with every repetition of an experiment. These flux offsets will possess Gaussian statistics whose distribution has a width given by the integrated low-frequency flux noise $W_{\rm LF}/2|I_q^p|$.⁵⁴ According to Eq. (6b), random flux offsets will distort the individual h_i by altering Φ_i^0 , thus shifting the intended Hamiltonian off target. If the random flux offsets are small, one can still expect the hardware to return $|\vec{s}_{gs}\rangle$ with high P_{gs} , but that probability will differ from predictions made from simulating the system in the absence of low-frequency flux noise. If the random flux offsets are comparable to the applied local flux bias on a given qubit at the critical point during annealing when the population statistics freeze, $W_{\rm LF}/2|I_{q|c}^{p} \sim h_{i}M_{\rm AFM}|I_{q|c}^{p}$, then the hardware could end up "solving" the wrong problem. Thus, low-frequency noise ultimately impacts the precision to which one can specify a problem instance. This issue is currently being investigated at a theoretical level.

In terms of a heuristic picture, it appears that QA, when run slowly with respect to the adiabatic limit, progresses as follows: first the system is initialized at an annealing parameter $\Phi_{ccjj}^{x}(t=0) = \Phi_{ccjj}^{m}$ where the gap between ground and first excited state is much greater than k_BT . The large gap ensures that the ground state is occupied with near certainty. Next, as Φ_{ccjj}^{x} is slowly lowered the system thermalizes to the environment. The environment strives to bring the qubit system to a Boltzmann distribution, though the ultimate achievement of that outcome can be hindered by differing transition rates between states. The system continues to thermalize until the qubit dynamics are significantly impeded by the reduction in Δ_q . Thereafter, despite the fact that the eigenenergies continue to diverge due to the growth of qubit persistent currents, the state of the processor will no longer evolve. Thus the population statistics become frozen at the levels achieved at some $\Phi_{ccjj}^{x}(t) > \Phi_{ccjj}^{x}(t_{f}) = \Phi_{ccjj}^{b}$.

To summarize this section of the paper, we have simulated the performance of the coupled eight-qubit system using a generalized Bloch-Redfield model to capture the physics of relaxation processes that couple the individual qubits to a thermal environment. The amplitude of the white noise spectral density sensed by each qubit was estimated from the widths of macroscopic resonant tunneling peaks. Comparison of the output of the model to the temperature-dependent probability distributions for three example problems indicated that the model captures the broad features seen in the data. The success histograms for all 6400 problem instances run on the hardware were roughly reproduced.

VI. DISCUSSION AND OPEN QUESTIONS

The experimental results in Sec. IV and the modeling in Sec. V present a compelling physical picture of how the state of our prototype processor evolves when run slowly in comparison to the adiabatic limit. These results have prompted some interesting conclusions and a series of open questions that we will briefly address below.

When an optimization problem instance is posed to our hardware and the annealing algorithm is run slowly, then the most probable result returned by the hardware is invariably the optimal solution, as encoded in the ground state. The remaining probability is distributed between low-lying states that are roughly within an energy window $\mathcal{O}(k_B T)$ above the energy of the ground state at the point in the annealing process where the population statistics freeze. Depending on the nature of the optimization problem, such low-lying states may still constitute acceptable solutions. This observation suggests two possible modes of running a QA processor in practice: (1) run a given optimization problem a statistically large number of times. Take all $|\vec{s}\rangle$ that are observed with probability greater than the readout resolution threshold and calculate $E(\vec{s})$ using Eq. (1). Take whatever $|\vec{s}\rangle$ provides the lowest E as the solution. (2) Run a given optimization problem once. Take the output $|\vec{s}\rangle$ and calculate $E(\vec{s})$ using Eq. (1). If E is less than some user-defined threshold, then accept the solution. If not, then iterate.

What happens when the CCJJ bias ramp time is reduced? Given the limited bandwidth of our external bias lines, we were unable to elicit a substantial change in population statistics. Thus, we were restricted to study the regime in which the thermalization times were much shorter than the annealing time. Consequently, we can only claim to have demonstrated QA, not AQO. Efforts are underway to build a new apparatus that will allow us to probe the regime in which thermalization times exceed the annealing time in an eightqubit unit cell.

How does the performance scale with problem size? The eight-qubit unit cell is too small to be used to address issues concerning scaling. The intention of this study was to provide a basic demonstration of what we believe to be a complete set of essential ingredients needed for building a scalable QA processor acting in concert. We will reserve a discussion of the operation of larger portions of a complete 128-qubit chip to a future publication.

How does one implement error correction in QA? The work presented in this paper is in much the same spirit as that of Ref. 55—operate a small scale device that "looks" like a basic quantum information processor and run it using the simplest algorithms known. We have made no attempts beyond statistical sampling to implement any form of error correction in these particular experiments. This is an active area of research at the moment.

To what precision must the qubit parameters $|I_q^p|$ and Δ_q be synchronized as a function of $\Phi_{ccjj}^x(t)$? Implicit in many models of AQO is the assumption that all of the qubits are identical throughout the annealing process. An examination of the data in Fig. 5 reveals that while $|I_q^p|$ is very uniform as a function of annealing parameter Φ_{ccjj}^x , there are clear discrepancies between values of Δ_q at the same bias Φ_{ccjj}^x . While we have demonstrated that our modest eight-qubit unit cell is capable of solving small-scale ISG problem instances, it is neither clear to what degree the asynchronization of $\Delta_q(t)$ may have impeded its performance nor what the implications of such asynchronization are for large-scale systems.

How do the higher excited states of the CCJJ rf SQUIDs affect performance? To our knowledge, this issue has not been addressed in the literature. We strongly advise against literal interpretations of many-qubit eigenspectra to energies that exceed that of the second excited state of an rf-SQUID serving as a qubit. This has consequences for studies regarding the ultimate utility of QA. Higher excited states provide fast interwell relaxation mechanisms that could limit failures during a computation.

VII. CONCLUSIONS

An eight-qubit unit cell that is part of a superconducting optimization processor has been experimentally investigated. This processor makes use of several scalable elements, including on-chip programmable flux sources, XY-addressable high-fidelity readouts, and the use of a limited number of global analog control lines to provide a variety of timedependent control signals to multiple devices. The processor was tested using a large set of randomly generated Ising spin-glass problem instances. The experimental results were shown to be consistent with the predictions of a quantummechanical theory in which the individual qubits are coupled to a thermal environment.

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APPENDIX: EXAMPLE PROBLEM INSTANCE SETTINGS

Parameter	Example A	Example B	Example C	
h_0	-1	-5/7	-3/7	
h_1	4/7	6/7	2/7	
h_2	5/7	-5/7	6/7	
h_3	4/7	-1	3/7	
h_4	-4/7	6/7	-5/7	
h_5	1/7	-3/7	2/7	
h_6	-5/7	-3/7	0	
h_7	4/7	-3/7	-2/7	
K_{04}	2/7	-6/7	-5/7	
K_{14}	4/7	-6/7	1/7	
<i>K</i> ₂₄	-1/7	0	0	
<i>K</i> ₃₄	-1/7	6/7	-3/7	
K_{05}	4/7	6/7	5/7	
<i>K</i> ₁₅	-2/7	1/7	5/7	
<i>K</i> ₂₅	-1/7	3/7	-1/7	
<i>K</i> ₃₅	6/7	-1/7	-4/7	

Parameter	Example A	Example B	Example C	Parameter	Example A	Example B	Example C
K_{06}	1/7	1	-6/7	<i>K</i> ₀₇	6/7	1/7	1/7
<i>K</i> ₁₆	1/7	3/7	5/7	K_{17}	2/7	4/7	-3/7
K_{26}	4/7	-5/7	-5/7	K ₂₇	4/7	6/7	-6/7
<i>K</i> ₃₆	-5/7	2/7	-1/7	<i>K</i> ₃₇	3/7	0	5/7

- ¹T. Kadowaki and H. Nishimori, Phys. Rev. E 58, 5355 (1998).
- ²E. Farhi, J. Goldstone, S. Gutmann, J. Lapan, A. Lundgren, and D. Preda, Science **292**, 472 (2001).
- ³G. E. Santoro, R. Martoňāk, E. Tosatti, and R. Car, Science **295**, 2427 (2002).
- ⁴G. E. Santoro and E. Tosatti, J. Phys. A 39, R393 (2006).
- ⁵A. T. Rezakhani, W.-J. Kuo, A. Hamma, D. A. Lidar, and P. Zanardi, Phys. Rev. Lett. **103**, 080502 (2009).
- ⁶B. Altshuler, H. Krovi, and J. Roland, arXiv:0908.2782 (unpublished).
- ⁷E. Farhi, J. Goldstone, D. Gosset, S. Gutmann, H. Meyer, and P. Shor, arXiv:0909.4766 (unpublished).
- ⁸B. Altshuler, H. Krovi, and J. Roland, arXiv:0912.0746 (unpublished).
- ⁹M. H. S. Amin and V. Choi, Phys. Rev. A 80, 062326 (2009).
- ¹⁰A. P. Young, S. Knysh, and V. N. Smelyanskiy, Phys. Rev. Lett. 104, 020502 (2010).
- ¹¹P. Ao and J. Rammer, Phys. Rev. Lett. **62**, 3004 (1989).
- ¹²A. M. Childs, E. Farhi, and J. Preskill, Phys. Rev. A 65, 012322 (2001).
- ¹³M. S. Sarandy and D. A. Lidar, Phys. Rev. Lett. **95**, 250503 (2005).
- ¹⁴J. Roland and N. J. Cerf, Phys. Rev. A **71**, 032330 (2005).
- ¹⁵S. Ashhab, J. R. Johansson, and F. Nori, Phys. Rev. A 74, 052330 (2006).
- ¹⁶M. Tiersch and R. Schützhold, Phys. Rev. A 75, 062313 (2007).
- ¹⁷A. Fubini, G. Falci, and A. Osterloh, New J. Phys. **9**, 134 (2007).
- ¹⁸M. J. O'Hara and D. P. O'Leary, Phys. Rev. A 77, 042319 (2008).
- ¹⁹M. H. S. Amin, P. J. Love, and C. J. S. Truncik, Phys. Rev. Lett. 100, 060503 (2008).
- ²⁰M. Steffen, W. van Dam, T. Hogg, G. Breyta, and I. Chuang, Phys. Rev. Lett. **90**, 067903 (2003).
- ²¹W. Kaminsky, S. Lloyd, and T. Orlando, arXiv:quant-ph/ 0403090 (unpublished).
- ²²W. M. Kaminsky and S. Lloyd, *Quantum Computing and Quantum Bits in Mesoscopic Systems* (Kluwer Academic, New York, USA, 2004).
- ²³M. Grajcar, A. Izmalkov, and E. Il'ichev, Phys. Rev. B 71, 144501 (2005).
- ²⁴M. Grajcar et al., Phys. Rev. Lett. 96, 047006 (2006).
- ²⁵ V. Zakosarenko, N. Bondarenko, S. H. W. van der Ploeg, A. Izmalkov, S. Linzen, J. Kunert, M. Grajcar, E. Il'ichev, and H.-G. Meyer, Appl. Phys. Lett. **90**, 022501 (2007).
- ²⁶J. Brooke, D. Bitko, T. F. Rosenbaum, and G. Aeppli, Science 284, 779 (1999).
- ²⁷J. Brooke, T. F. Rosenbaum, and G. Aeppli, Nature (London)

413, 610 (2001).

- ²⁸R. Harris et al., Phys. Rev. B 81, 134510 (2010).
- ²⁹R. Harris, T. Lanting, A. J. Berkley, J. Johansson, M. W. Johnson, P. Bunyk, E. Ladizinsky, N. Ladizinsky, T. Oh, and S. Han, Phys. Rev. B **80**, 052506 (2009).
- ³⁰A. Berkley, M. Johnson, P. Bunyk, R. Harris, J. Johansson, T. Lanting, E. Ladizinsky, E. Tolkacheva, M. Amin, and G. Rose, arXiv:0905.0891 (unpublished).
- ³¹M. W. Johnson *et al.*, Supercond. Sci. Technol. **23**, 065004 (2010).
- ³²F. Barahona, J. Phys. A **15**, 3241 (1982).
- ³³F. Barahona, Phys. Rev. B **49**, 12864 (1994).
- ³⁴S. Han, J. Lapointe, and J. E. Lukens, Phys. Rev. B **46**, 6338 (1992).
- ³⁵T. P. Orlando, J. E. Mooij, L. Tian, C. H. van der Wal, L. S. Levitov, S. Lloyd, and J. J. Mazo, Phys. Rev. B **60**, 15398 (1999).
- ³⁶R. H. Koch, G. A. Keefe, F. P. Milliken, J. R. Rozen, C. C. Tsuei, J. R. Kirtley, and D. P. DiVincenzo, Phys. Rev. Lett. **96**, 127001 (2006).
- ³⁷F. G. Paauw, A. Fedorov, C. J. P. M. Harmans, and J. E. Mooij, Phys. Rev. Lett. **102**, 090501 (2009).
- ³⁸T. H. Cormen, C. E. Leiserson, R. L. Rivest, and C. Stein, *Introduction to Algorithms* (MIT Press, Cambridge, MA, 2001).
- ³⁹ J. Johansson, M. H. S. Amin, A. J. Berkley, P. Bunyk, V. Choi, R. Harris, M. W. Johnson, T. M. Lanting, S. Lloyd, and G. Rose, Phys. Rev. B **80**, 012507 (2009).
- ⁴⁰T. Hogg, Phys. Rev. A **67**, 022314 (2003).
- ⁴¹ A. Childs, E. Farhi, J. Goldstone, and S. Gutmann, Quantum Inf. Comput. 2, 181 (2002).
- ⁴² A. P. Young, S. Knysh, and V. N. Smelyanskiy, Phys. Rev. Lett. 101, 170503 (2008).
- ⁴³ A. Izmalkov, M. Grajcar, E. Il'ichev, N. Oukhanski, T. Wagner, H.-G. Meyer, W. Krech, M. H. S. Amin, A. M. van den Brink, and A. M. Zagoskin, Europhys. Lett. **65**, 844 (2004).
- ⁴⁴D. M. Berns, W. D. Oliver, S. O. Valenzuela, A. V. Shytov, K. K. Berggren, L. S. Levitov, and T. P. Orlando, Phys. Rev. Lett. **97**, 150502 (2006).
- ⁴⁵R. Harris et al., Phys. Rev. Lett. **101**, 117003 (2008).
- ⁴⁶U. Weiss, *Quantum Dissipative Systems* (World Scientific, Singapore, 1993).
- ⁴⁷ R. J. Schoelkopf, A. A. Clerk, S. M. Girvin, K. W. Lehnert, and M. H. Devoret, in *Quantum Noise in Mesoscopic Physics*, edited by Y. V. Nazarov and Y. M. Blanter (Springer, New York, USA, 2003).
- ⁴⁸F. Wellstood, C. Urbina, and J. Clarke, Appl. Phys. Lett. **85**, 5296 (2004).
- ⁴⁹K. Blum, Density Matrix Theory and Applications (Plenum, New

York, 1981).

- ⁵⁰M. H. S. Amin, C. J. S. Truncik, and D. V. Averin, Phys. Rev. A 80, 022303 (2009).
- ⁵¹M. H. S. Amin and D. V. Averin, Phys. Rev. Lett. **100**, 197001 (2008).
- ⁵²T. Lanting et al., Phys. Rev. B **79**, 060509(R) (2009).
- ⁵³F. Deppe, M. Mariantoni, E. P. Menzel, S. Saito, K. Kakuyanagi, H. Tanaka, T. Meno, K. Semba, H. Takayanagi, and R. Gross, Phys. Rev. B **76**, 214503 (2007).
- ⁵⁴J. M. Martinis, S. Nam, J. Aumentado, K. M. Lang, and C. Urbina, Phys. Rev. B 67, 094510 (2003).
- ⁵⁵L. DiCarlo et al., Nature (London) 460, 240 (2009).